

Technical Data Sheet

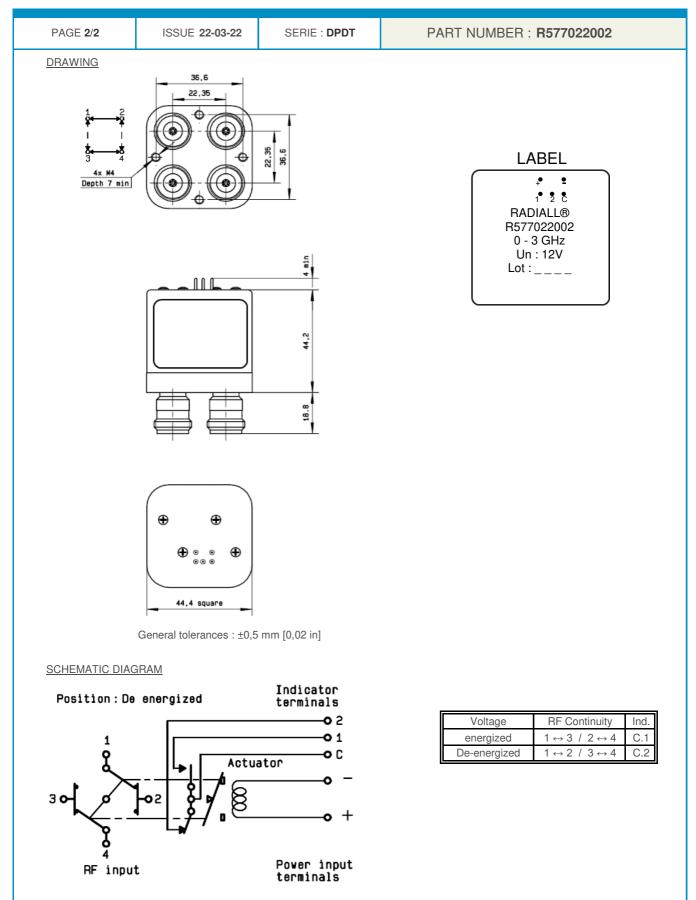
DPDT Ramses N 3GHz Failsafe Indicators 12Vdc Pins Terminals

	Frequency ra	ange			0 - 3 GHz				
	Impedance			:	50 Ohms				
	Frequency (GHz)		DC - 1	1 - 2	2 - 3				
	VSWR max		1.15	1.20	1.25				
	Insertion loss max Isolation min		0.15 dB 85 dB	0.20 dB 80 dB	0.25 dB 75 dB				
	Average pov		700 W	500 W	400 W				
<u>ELE(</u>	CTRICAL CHA	RACTERIS	<u>TICS</u>						
	Actuator				FAILSAFE				
Nominal current ** Actuator voltage (Vcc)					: 340 mA : 12V (10.2 to	12\/\			
Terminals						(250°C max. / 30 s	sec.)		
	Indicator rati	ng			1 W / 30 V /				
Life Switching Time*** Construction				2.5 million cycles 2 < 15 ms 2 Splashproof 2 < 215 g					
<u>ENV</u>	Weight	_ CHARACT	ERISTICS		. < 215 g				
	Operating temperature range Storage temperature range			: -40°C to +8 : -55°C to +8			zoHs		
(*	Average pov		er RF Path)						
(** (***	At 25° C ±10 Nominal volt						ON	PLIAT	



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